Electronic Patent Application Fee Transmittal							
Application Number:	10811808						
Filing Date:	30-Mar-2004						
Title of Invention:	Gallium nitride (GaN)-based semiconductor light emitting diode and method for manufacturing the same						
First Named Inventor:	Seung Wan Chae						
Filer:	Benjamin J. Hauptman/Ayesha Wilson						
Attorney Docket Number:	2336-257						
Filed as Large Entity							
Utility Filing Fees							
Description		Fee Code	Quantity	Amount	Sub-Total in USD(\$)		
Basic Filing:							
Pages:							
Claims:							
Miscellaneous-Filing:							
Petition:							
Patent-Appeals-and-Interference:							
Post-Allowance-and-Post-Issuance:							
Extension-of-Time:							
Extension - 1 month with \$0 paid		1251	1	120	120		

Description	Fee Code	Quantity	Amount	Sub-Total in USD(\$)				
Miscellaneous:								
Request for continued examination	1801	1	790	790				
	Tota	910						